

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error	Errors
1	BRS	10	thin adj film near nanowire	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 16:00			0
2	BRS	22	nanowire same gate same drain same source and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 16:02			0
3	BRS	14	nanowire same gate same drain same source and diode and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/24 16:03			0
4	BRS	35	nanowire same gate same drain same	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 16:54			0
5	BRS	14	nanowire and gate and (drain or source) and cathode and anode and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:04			0
6	BRS	45	diode and nanos and gate and (drain or source) and cathode and anode and diode and driver and memory and logic and align\$ and single adj crystal\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:26			0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error
7	BRS	1	nano\$ and gate and (drain or source) and cathode and anode and diode and matrix near driv\$ and memory and logic and align\$ and single adj crystals\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:14		0
8	BRS	22	nano\$ not nanometer and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:15		0
9	BRS	22	(nanow\$ or nanos\$ or nanop\$ or nanot\$) and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:17		0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Error
10	BRS	6	(nanow\$ or nanost\$ or nanop\$ or nanot\$) and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:46		0
11	BRS	1	nanos\$ with current and gate and (drain or source) and cathode and anode and diode and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:25		0
12	BRS	31	nanos\$ with current and gate and (drain or source) and diode and memory and logic and align\$ and single adj crystals\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:28		0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Errors
13	BRS	3	(nanowire or nanostructure or nanoparticle or nanotube) and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:47		0
14	BRS	3	(nanowire or nanostructure or nanoparticle or nanotube) and gate and (drain or source) and cathode and anode and driv\$ and memory and logic and align\$ and single adj cry	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:48		0
15	BRS	54	(nanowire or nanostructure or nanoparticle or nanotube) and gate and (drain or source) and driv\$ and memory and logic and align\$ and single adj crystals	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:49		0

	Type	Hits	Search Text	DBs	Time Stamp	C	o	r	d	E
						m	m	r	r	
						e	n	e	s	
						s	t	s	i	
									t	
									i	
									o	
16	BRS	3	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and (drain or source) and driv\$ and memory and logic and align\$ and single adj crystals\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 17:51					0
17	BRS	5	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and (drain or source) and memory and logic and align\$ and single adj crystals\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 18:14					0
18	IS&R	2	("6314019").PN .	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 18:08					0
19	BRS	4	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and drain and source and memory and logic and align\$	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 18:20					0

	Type	Hits	Search Text	DBs	Time Stamp	Comments	Errors
20	BRS	35	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and drain and source and aligns	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 18:21		0
21	BRS	13	(nanowire or nanostructure or nanoparticle or nanotube) near substrate and gate and drain and source and memory and aligns	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 19:04		0
22	BRS	2	(nanowire or nanostructure or nanoparticle or nanotube) near channel and gate and drain and source and memory and aligns	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 19:06		0
23	BRS	24	(nanowire or nanostructure or nanoparticle or nanotube) near channel and gate and drain and source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/09/25 19:06		0